A44

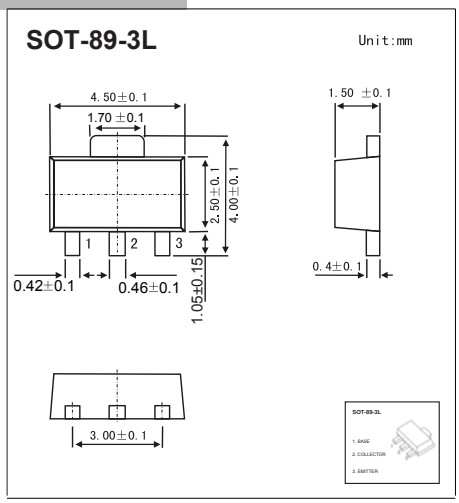
SOT-89 Plastic-Encapsulate Transistors

FEATURES

- Low Collector-Emitter Saturation Voltage
- High Breakdown Voltage
- TRANSISTOR (NPN)

MECHANICAL DATA

- Case style:SOT-89 -3L molded plastic
- Mounting position:any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	400	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	200	mA
I_{CM}	Collector Current -Pulsed	300	mA
P_C	Collector Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	250	℃/W
T_j	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55~+150	℃

PACKAGE INFORMATION

Device	Package	Shipping
A44	SOT-89	1000/Tape&Reel

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=100μA,I_E=0	400			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$*	I_C=1mA,I_B=0	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=10μA,I_C=0	6			V
Collector cut-off current	I_{CBO}	V_{CB}=400V,I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}=4V,I_C=0			0.1	μA
DC current gain	$h_{FE(1)}$*	V_{CE}=10V, I_C=1mA	40			
	$h_{FE(2)}$*	V_{CE}=10V, I_C=10mA	50		200	
	$h_{FE(3)}$*	V_{CE}=10V, I_C=50mA	45			
	$h_{FE(4)}$*	V_{CE}=10V, I_C=100mA	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$*	I_C=1mA,I_B=0.1mA			0.4	V
		I_C=10mA,I_B=1mA			0.5	V
		I_C=50mA,I_B=5mA			0.75	V
Base-emitter saturation voltage	$V_{BE(sat)}$*	I_C=10mA,I_B=1mA			0.75	V
Collector output capacitance	C_{ob}	V_{CB}=20V, I_E=0, f=1MHz			7	pF
Emitter input capacitance	C_{ib}	V_{BE}=0.5V, I_C=0, f=1MHz			130	pF

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

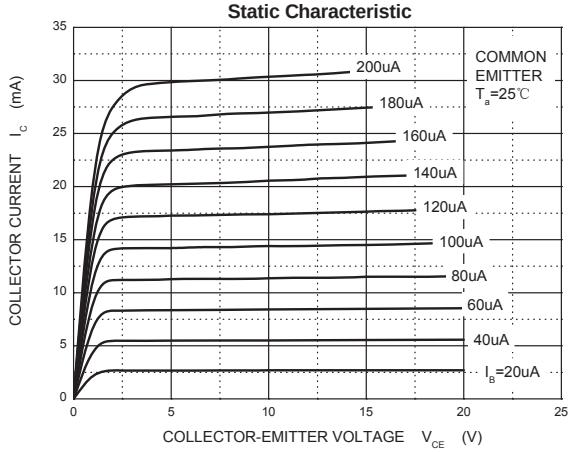
■ Marking

Marking	A44

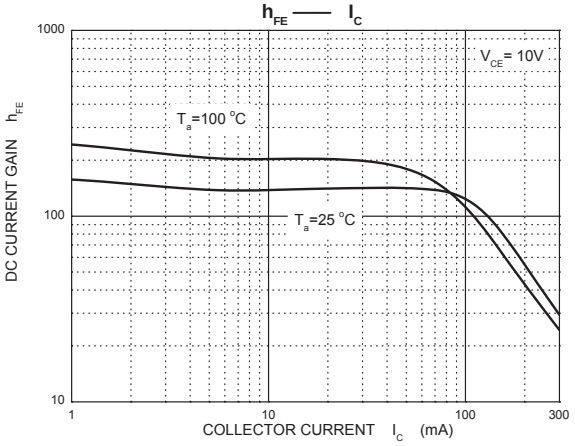
RATINGS AND CHARACTERISTIC CURVES

Typical Characteristics

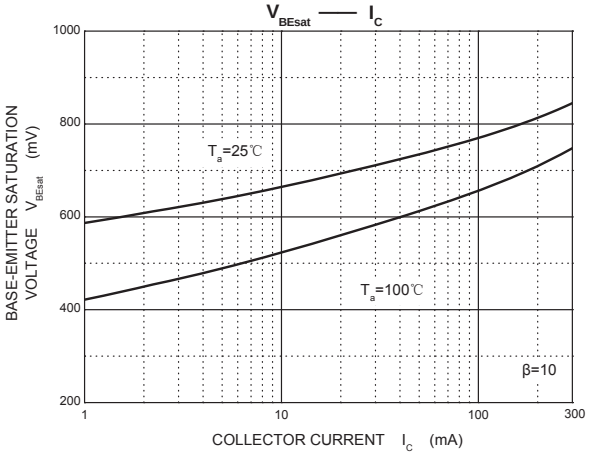
Static Characteristic



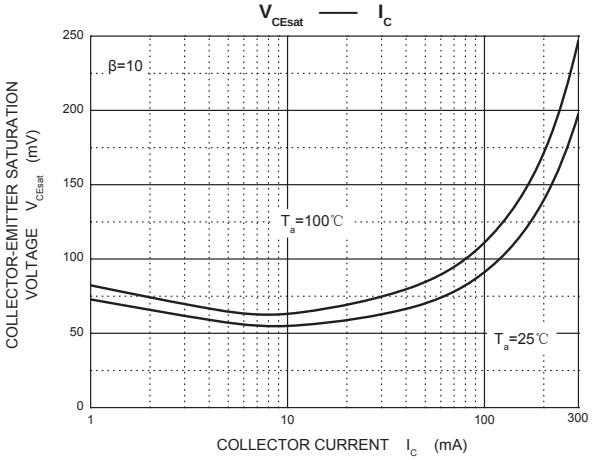
h_{FE} —— I_C



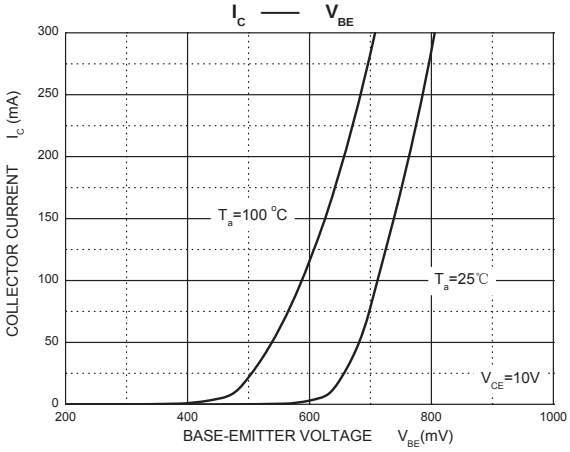
V_{BEsat} —— I_C



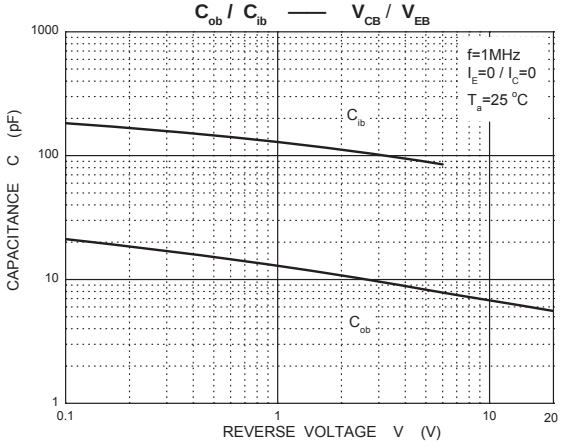
V_{CEsat} —— I_C



I_C —— V_{BE}



C_{ob} / C_{ib} —— V_{CB} / V_{EB}



P_c —— T_a